

## ESDALC14V2-2BP5 ESDALC25-2BP5

## Low capacitance TRANSIL™ array for ESD protection

## Main applications

Where transient overvoltage protection in ESD sensitive equipment is required, such as:

- Computers
- Printers
- Communication systems such as xDSL modem
- Video equipment

This device is particularly adapted to the protection of symmetrical systems

### **Features**

- 2 Bidirectional Transil functions
- Breakdown voltage: V<sub>BR</sub> = 14.2 V and 25 V minimum
- Low leakage current: < 1 µA</p>
- Low diode capacitance: 14 and 8 pF at 3 V
- Very small PCB area < 2.6 mm<sup>2</sup>

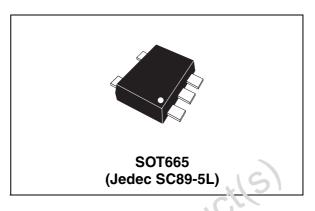
## **Description**

The ESDALCxx-2BP5 is a moncrithic array designed to protect up to 2 line: against ESD transients.

The device is ideal for situations where board space saving is required.

### Benefits

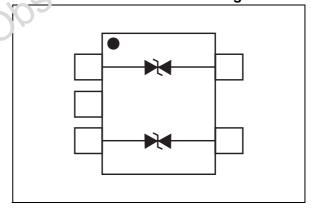
- ▼ High ESD protection level
- High integration
- Suitable for high density boards



#### **Order codes**

Part Number	Marking
ESDALC14V2-2BP3	А3
ESDALC%5-25P5	A4

### ESDA! Cxx-2BP5 Functional diagram



### Complies with the following standards

#### IEC61000-4-2

Level 4 15 kV (air discharge)

8 kV(contact discharge)

MIL STD 883E - Method 3015-7 Class 3

25 kV HBM (Human Body Model)

TM: TRANSIL is a trademark of STMicroelectronics

Rev 1

1/6

## 1 Characteristics

Table 1. Absolute Ratings  $(T_{amb} = 25^{\circ}C)$ 

Symbol	Parameter	Value	Unit
P <sub>PP</sub>	Peak pulse power (8/20 μs) <sup>(1)</sup>	50	W
T <sub>j</sub>	Junction temperature	150	°C
T <sub>stg</sub>	Storage temperature range	-55 to +150	°C
$T_L$	Maximum lead temperature for soldering during 10s	260	°C
T <sub>op</sub>	Operating temperature range <sup>(2)</sup>	-40 to +150	°C

- 1. For a surge greater than the maximum values, the diode will fail in short circuit
- 2. The values of the operating parameters versus temperature are given through curves and  $\alpha T$  parameter.

## 1.1 Electrical characteristics (Tamb = 25°C)

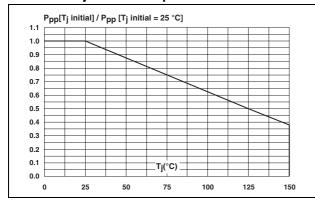
Symbol	Parameter	29,01
V <sub>RM</sub>	Stand-off voltage	<b>↑</b> 1
V <sub>BR</sub>	Breakdown voltage	
V <sub>CL</sub>	Clamping voltage	
I <sub>RM</sub>	Leakage current	V <sub>CL</sub> V <sub>BR</sub> V <sub>RM</sub>
I <sub>PP</sub>	Peak pulse current	I <sub>RM</sub> V <sub>RM</sub> V <sub>BR</sub> V <sub>CL</sub>
αΤ	Voltage temperature coefficient	
$V_{F}$	Forward voltage drop	Slope: 1/R <sub>d</sub>
С	Capacitance	I <sub>PP</sub>
R <sub>d</sub>	Dynamic resistance	
	240	

8/0	V <sub>BR</sub> @ I <sub>R</sub>		I <sub>RM</sub> @ V <sub>RM</sub>		R <sub>d</sub>	α <b>T</b>	С	
Part Numbers	min.	max.		max.		typ.	max.	typ. 3V bias
	V	V	mA	μΑ	V	Ω	10 <sup>-4</sup> /°C	pF
ESDALC14V2-2BP5	14.2	18	1	1	12	1.5	7	14
ESDALC25-2BP5	25	29.7	1	1	24	1.3	8	8

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Figure 1. Peak pulse power versus initial junction temperature

Figure 2. Peak pulse power versus exponential pulse duration



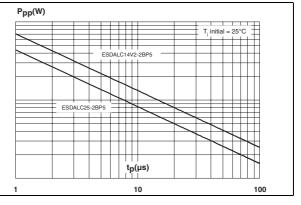
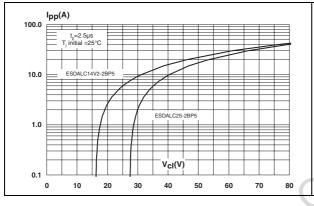


Figure 3. Clamping voltage versus peak pulse Figure 4. current (maximum values, rectangular waveform)

Junction capacitance versus reverse applied voltage (typical values)



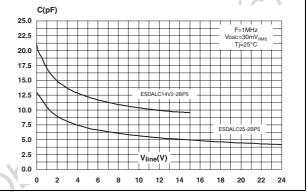
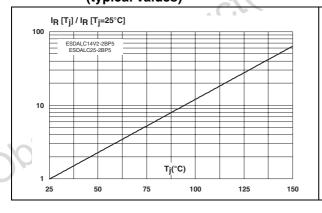
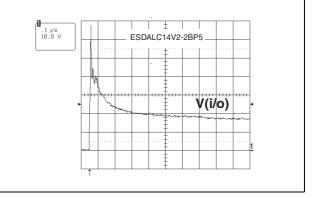


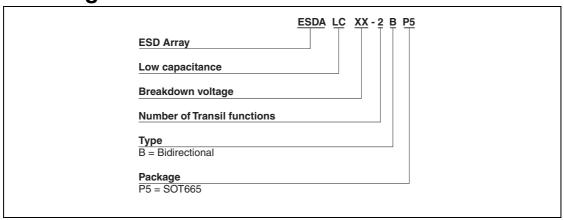
Figure 5. Relative variation of leakage current Figure 6. versus junction temperature (typical values)

ESD response to IEC61000-4-2 (air discharge 15kV, positive surge)





#### **Ordering information scheme** 2



#### Package mechanical data 3

#### SOT665 package 3.1

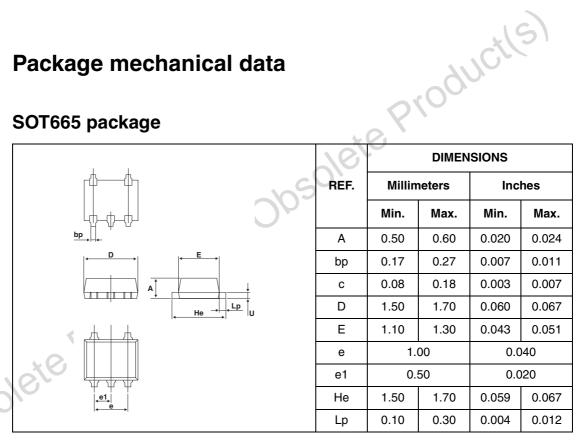
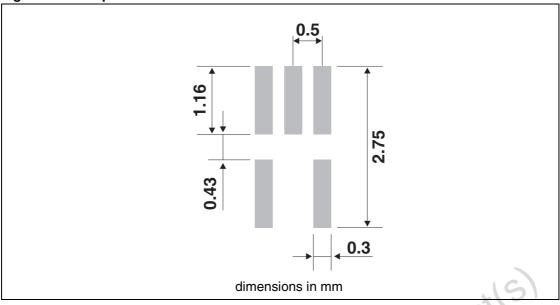


Figure 7. Footprint dimensions



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

# 4 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
ESDALC14V2-2BP5	А3	SOT665	2.9 mg	3000	Tape & reel
ESDALC25-2BP5	A4	301003	2.9 mg	3000	ιαρε α τεει

## 5 Revision history

Date	Revision	Changes
08-Dec-2005	1	First issue

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